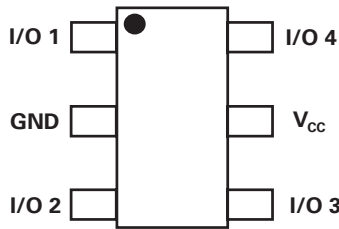


SRV05-4HTG-D, 5V 10A TVS Diode Array

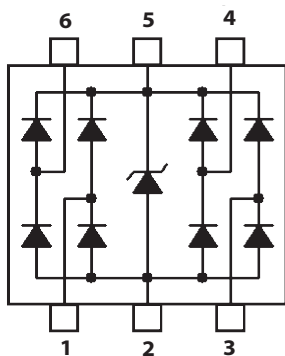


Pinout



Top View

Functional Block Diagram



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Description

The SRV05-4HTG-D integrates low capacitance rail-to-rail diodes with an additional zener diode to protect each I/O pin against ESD and high surge events. This robust device can safely absorb 10A surge current per IEC61000-4-5 ($t_p=8/20\mu s$) without performance degradation and a minimum $\pm 30kV$ ESD per IEC 61000-4-2. Their very low loading capacitance also makes them ideal for

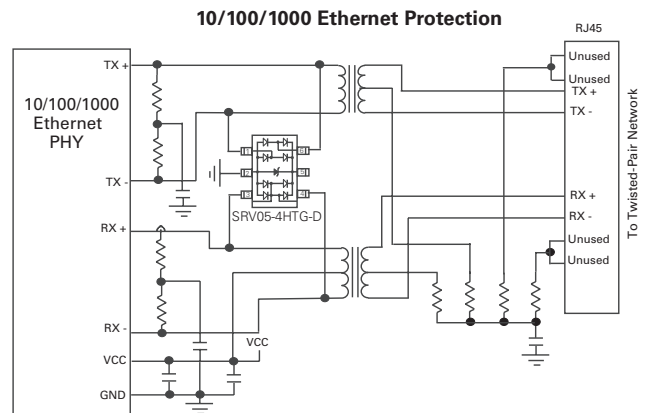
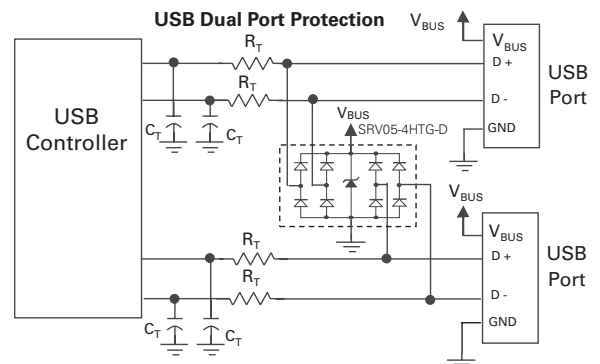
Features

- ESD, IEC 61000-4-2, $\pm 30kV$ contact, $\pm 30kV$ air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, 10A (8/20 μs as defined in IEC 61000-4-5 2nd edition)
- Low capacitance of 1pF (TYP) per I/O
- Low leakage current of 0.5 μA (MAX) at 5V
- Small SOT23-6 (JEDEC MO-178) packaging
- Halogen free, lead free and RoHS compliant
- Moisture Sensitivity Level (MSL -1)

Applications

- LCD/PDPT TVs
- Monitors
- Notebooks
- 10/100/1000 Ethernet
- Firewire
- Set Top Boxes
- Flat Panel Displays
- Portable Medical

Application Examples



Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I_{PP}	Peak Current ($t_p=8/20\mu s$)	10	A
P_{PK}	Peak Pulse Power ($t_p=8/20\mu s$)	150	W
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Notes:

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics ($T_{OP}=25^\circ C$)

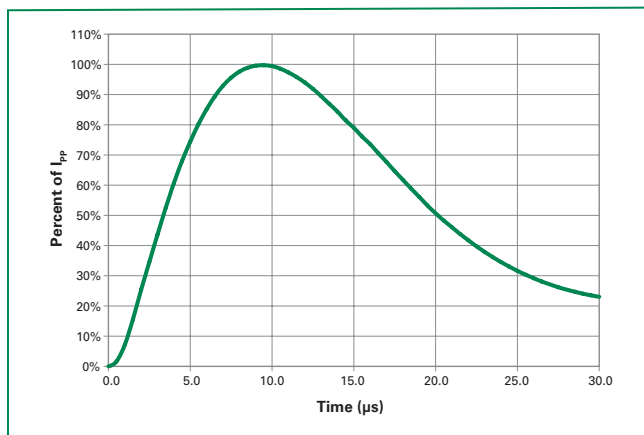
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R = 1\mu A$, I/O to GND			6	V
Breakdown Voltage	V_{BR}	$I_R = 1mA$, I/O to GND	6	8.5		V
Reverse Leakage Current	I_{LEAK}	$V_R=5V$, I/O to GND		0.1	0.5	μA
Clamp Voltage ¹	V_C	$I_{PP}=5A$, $t_p=8/20\mu s$, I/O to GND		11.7	13	V
		$I_{PP}=8A$, $t_p=8/20\mu s$, I/O to GND		12.5	14	V
		$I_{PP}=10A$, $t_p=8/20\mu s$, I/O to GND		13.2	15	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p=100ns$, I/O to GND		0.28		Ω
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact Discharge)	± 30			kV
		IEC 61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, $f=1MHz$, I/O to GND		1	3	pF
	$C_{I/O-I/O}$	Reverse Bias=0V, $f=1MHz$, I/O to I/O		0.5		pF

Notes:

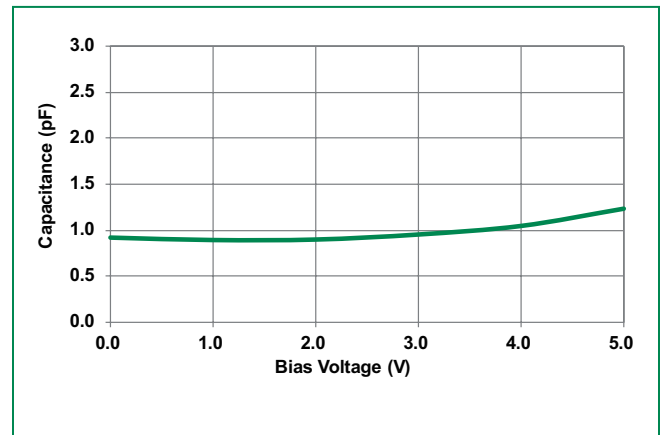
1Parameter is guaranteed by design and/or component characterization.

 2 Transmission Line Pulse (TLP) test setting : Std.TDR(50 Ω), $t_p=100ns$, $t_r=0.2ns$ ITLP and VTLP averaging window: start $t_1=70ns$ to end $t_2=80ns$

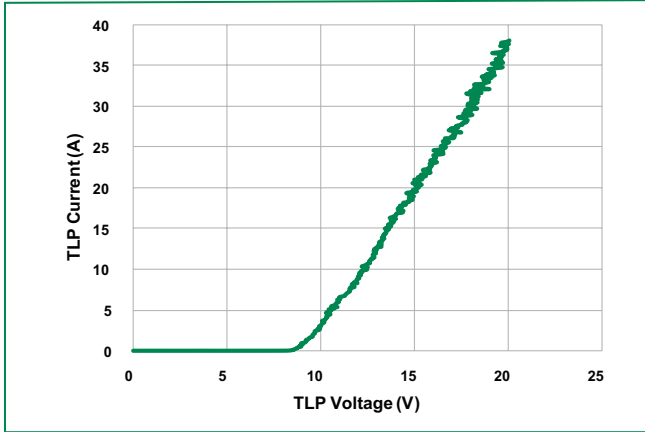
8/20 μs Pulse Waveform



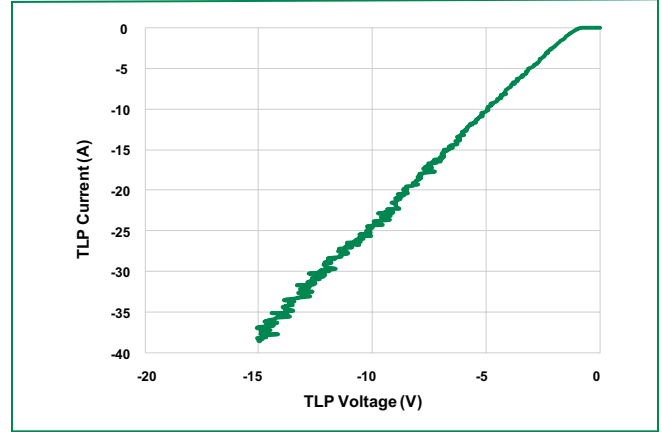
Capacitance vs. Reverse Bias



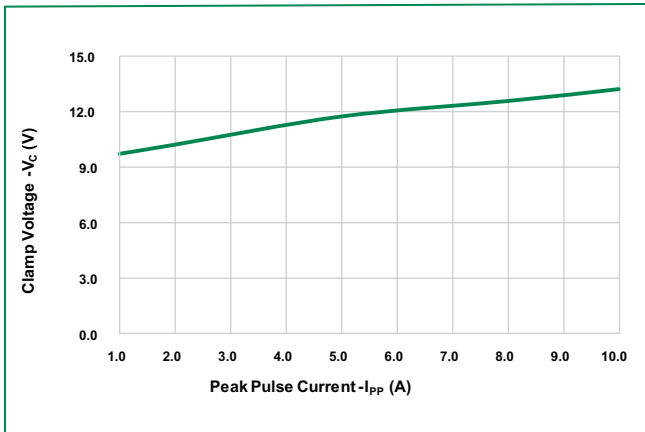
Positive Transmission Line Pulsing (TLP) Plot



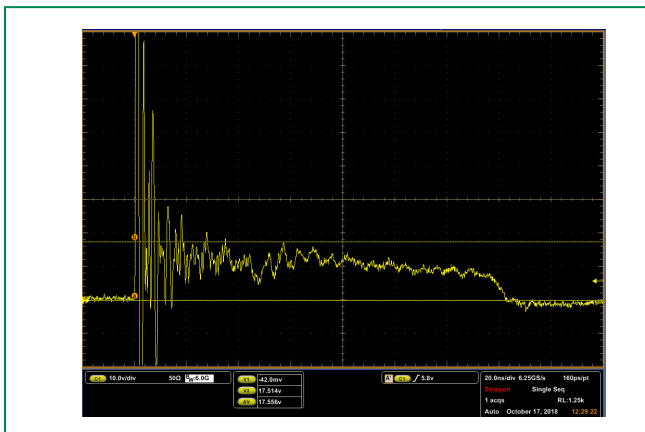
Negative Transmission Line Pulsing (TLP) Plot



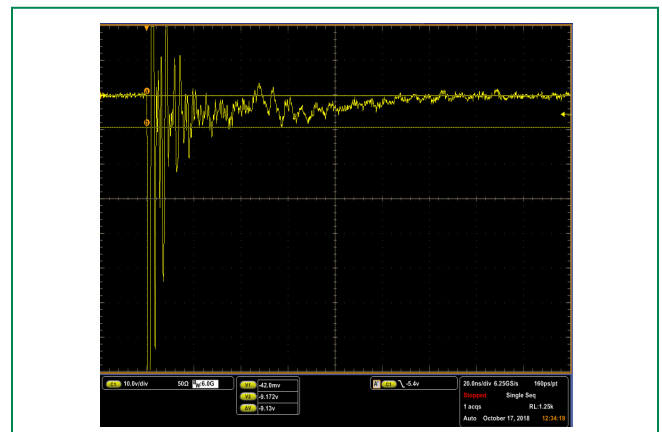
Clamping Voltage vs. Peak Pulse Current



IEC 61000-4-2 +8 kV Contact ESD Clamping Voltage



IEC 61000-4-2 -8 kV Contact ESD Clamping Voltage



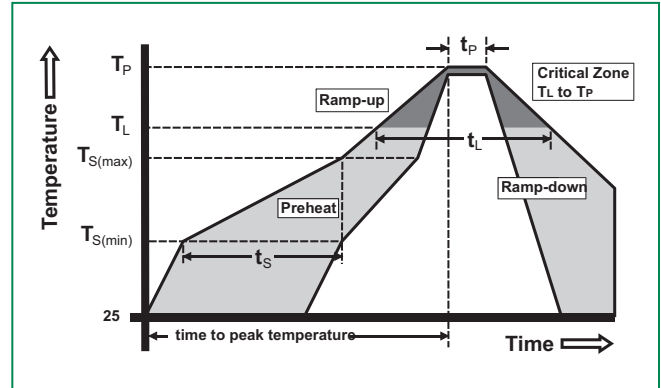
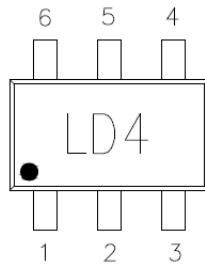
Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C

Ordering Information

Part Number	Package	Min. Order Qty.
SRV05-4HTG-D	SOT23-6	3000

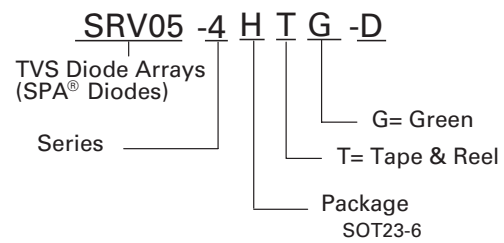
Part Marking System



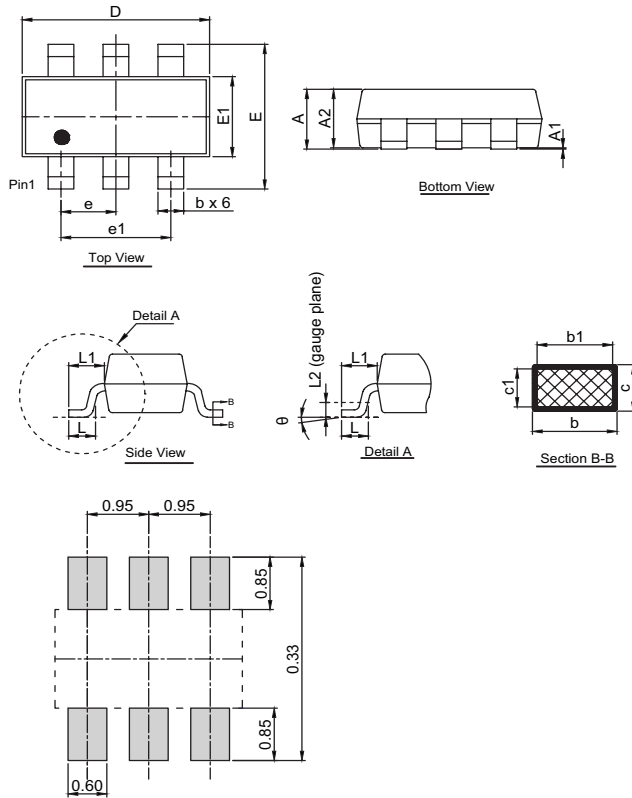
Product Characteristics

Lead Plating	Matte Tin
Lead Material	Copper Alloy
Lead Conpanarity	0.004 inches(0.102mm)
Substrate Material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

Part Numbering System



Package Dimensions - SOT23-6

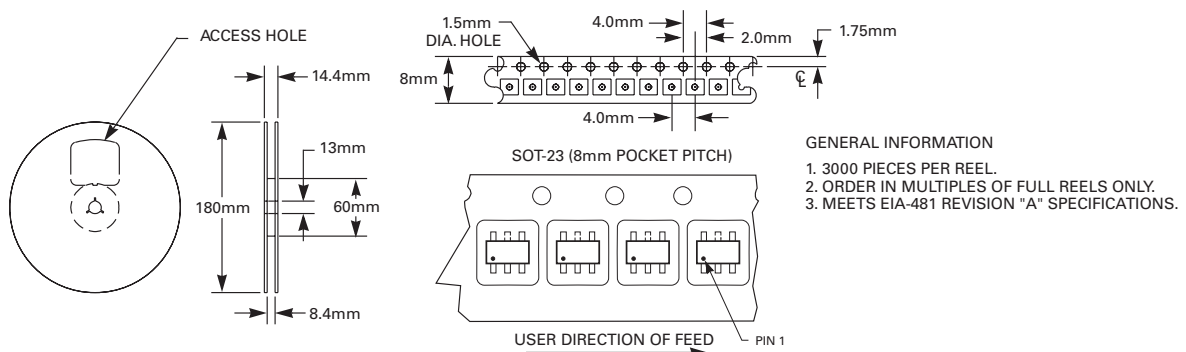


Symbol	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
A	-	-	1.45	-	-	0.057
A1	0.00	-	0.15	0.000	-	0.006
A2	0.90	1.15	1.30	0.035	0.045	0.051
b	0.30	-	0.50	0.012	-	0.020
b1	0.30	0.40	0.45	0.012	0.016	0.018
c	0.08	-	0.22	0.003	-	0.009
c1	0.08	0.13	0.20	0.003	0.005	0.008
D	2.70	2.90	3.05	0.106	0.114	0.120
E	2.60	2.80	3.00	0.102	0.110	0.118
E1	1.45	1.60	1.75	0.057	0.063	0.069
e	0.95 BSC			0.037 BSC		
e1	1.90 BSC			0.075 BSC		
L	0.30	0.50	0.60	0.012	0.020	0.024
L1	0.60 REF			0.024 REF		
L2	0.25 BSC			0.010 BSC		
θ	0°	4°	8°	0°	4°	8°

Recommended soldering pad layout (unit :mm)
Drawing#: H02-B

Embossed Carrier Tape & Reel Specification – SOT23-6

8mm TAPE AND REEL



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